

# RF Power Field Effect Transistors

## N-Channel Enhancement-Mode Lateral MOSFETs

Designed for CDMA base station applications with frequencies from 1880 to 2025 MHz. Can be used in Class AB and Class C for all typical cellular base station modulation formats.

- Typical Doherty Single-Carrier W-CDMA Performance:  $V_{DD} = 28$  Volts,  $I_{DQA} = 500$  mA,  $V_{GSB} = 1.2$  Vdc,  $P_{out} = 24$  Watts Avg., IQ Magnitude Clipping, Channel Bandwidth = 3.84 MHz, Input Signal PAR = 9.9 dB @ 0.01% Probability on CCDF.

| Frequency | $G_{ps}$ (dB) | $\eta_D$ (%) | Output PAR (dB) | ACPR (dBc) |
|-----------|---------------|--------------|-----------------|------------|
| 1880 MHz  | 16.0          | 42.8         | 8.0             | -31.0      |
| 1920 MHz  | 16.0          | 43.7         | 8.1             | -32.6      |
| 2025 MHz  | 15.9          | 42.0         | 8.1             | -31.2      |

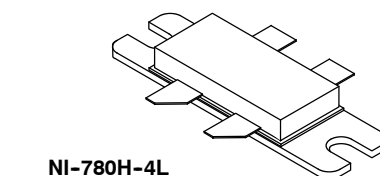
- Capable of Handling 10:1 VSWR, @ 30 Vdc, 1920 MHz, 160 Watts CW <sup>(1)</sup> Output Power (3 dB Input Overdrive from Rated  $P_{out}$ )
- Typical  $P_{out}$  @ 3 dB Compression Point  $\approx 170$  Watts <sup>(1)</sup>

### Features

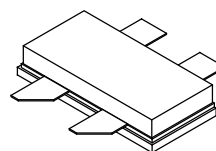
- Designed for Wide Instantaneous Bandwidth Applications.  $VBW_{res} \approx 240$  MHz.
- Designed for Wideband Applications that Require 160 MHz Signal Bandwidth
- Production Tested in a Symmetrical Doherty Configuration
- 100% PAR Tested for Guaranteed Output Power Capability
- Characterized with Large-Signal Load-Pull Parameters and Common Source S-Parameters
- Internally Matched for Ease of Use
- Integrated ESD Protection
- Greater Negative Gate-Source Voltage Range for Improved Class C Operation
- Designed for Digital Predistortion Error Correction Systems
- NI-780H-4L in Tape and Reel. R3 Suffix = 250 Units, 56 mm Tape Width, 13-inch Reel.
- NI-780S-4L, NI-780GS-4L in Tape and Reel. R3 Suffix = 250 Units, 32 mm Tape Width, 13-inch Reel.

**MRF8P20140WHR3**  
**MRF8P20140WHSR3**  
**MRF8P20140WGHSR3**

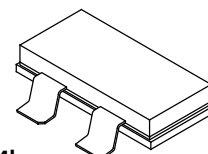
**1880-2025 MHz, 24 W AVG., 28 V**  
**SINGLE W-CDMA**  
**LATERAL N-CHANNEL**  
**RF POWER MOSFETs**



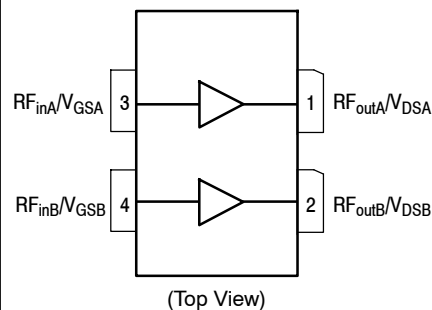
**NI-780H-4L**  
**MRF8P20140WHR3**



**NI-780S-4L**  
**MRF8P20140WHSR3**



**NI-780GS-4L**  
**MRF8P20140WGHSR3**



**Figure 1. Pin Connections**

1.  $P_{3dB} = P_{avg} + 7.0$  dB where  $P_{avg}$  is the average output power measured using an unclipped W-CDMA single-carrier input signal where output PAR is compressed to 7.0 dB @ 0.01% probability on CCDF.

**Table 1. Maximum Ratings**

| Rating                                                                     | Symbol    | Value       | Unit      |
|----------------------------------------------------------------------------|-----------|-------------|-----------|
| Drain-Source Voltage                                                       | $V_{DSS}$ | -0.5, +65   | Vdc       |
| Gate-Source Voltage                                                        | $V_{GS}$  | -6.0, +10   | Vdc       |
| Operating Voltage                                                          | $V_{DD}$  | 32, +0      | Vdc       |
| Storage Temperature Range                                                  | $T_{stg}$ | -65 to +150 | °C        |
| Case Operating Temperature                                                 | $T_C$     | 125         | °C        |
| Operating Junction Temperature (1,2)                                       | $T_J$     | 225         | °C        |
| CW Operation @ $T_C = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | CW        | 140<br>0.66 | W<br>W/°C |

**Table 2. Thermal Characteristics**

| Characteristic                                                                                                                                                                                                                                                                                    | Symbol          | Value (2,3)  | Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------|------|
| Thermal Resistance, Junction to Case<br>Case Temperature $80^\circ\text{C}$ , 24 W CW, 28 Vdc, $I_{DQA} = 500\text{ mA}$ , $V_{GSB} = 1.2\text{ Vdc}$ , 1920 MHz<br>Case Temperature $96^\circ\text{C}$ , 130 W CW (3), 28 Vdc, $I_{DQA} = 500\text{ mA}$ , $V_{GSB} = 1.2\text{ Vdc}$ , 1920 MHz | $R_{\theta JC}$ | 0.68<br>0.40 | °C/W |

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class |
|---------------------------------------|-------|
| Human Body Model (per JESD22-A114)    | 2     |
| Machine Model (per EIA/JESD22-A115)   | A     |
| Charge Device Model (per JESD22-C101) | IV    |

**Table 4. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics (4)**

|                                                                                                   |           |   |   |    |                 |
|---------------------------------------------------------------------------------------------------|-----------|---|---|----|-----------------|
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 65\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 10 | $\mu\text{Adc}$ |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 28\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 5  | $\mu\text{Adc}$ |
| Gate-Source Leakage Current<br>( $V_{GS} = 5\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )              | $I_{GSS}$ | — | — | 1  | $\mu\text{Adc}$ |

**On Characteristics (4,5)**

|                                                                                                                              |              |     |     |     |     |
|------------------------------------------------------------------------------------------------------------------------------|--------------|-----|-----|-----|-----|
| Gate Threshold Voltage<br>( $V_{DS} = 10\text{ Vdc}$ , $I_D = 200\text{ }\mu\text{Adc}$ )                                    | $V_{GS(th)}$ | 1.1 | 1.8 | 2.6 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DS} = 28\text{ Vdc}$ , $I_{DA} = 500\text{ mAdc}$ )                                          | $V_{GSA(Q)}$ | —   | 2.6 | —   | Vdc |
| Fixture Gate Quiescent Voltage (6)<br>( $V_{DD} = 28\text{ Vdc}$ , $I_{DA} = 500\text{ mAdc}$ , Measured in Functional Test) | $V_{GGA(Q)}$ | 4.5 | 5.2 | 6.0 | Vdc |
| Drain-Source On-Voltage<br>( $V_{GS} = 10\text{ Vdc}$ , $I_D = 2\text{ Adc}$ )                                               | $V_{DS(on)}$ | 0.1 | 0.2 | 0.3 | Vdc |

1. Continuous use at maximum temperature will affect MTTF.
2. MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.
3. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes – AN1955.
4. Exceeds recommended operating conditions. See CW operation data in Maximum Ratings table.
5. Each side of device measured separately.
6.  $V_{DDA}$  and  $V_{ddb}$  must be tied together and powered by a single DC power supply.
7.  $V_{GG} = 2.0 \times V_{GS(Q)}$ . Parameter measured on Freescale Test Fixture, due to resistive divider network on the board. Refer to Test Circuit schematic.

(continued)

**Table 4. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (continued)

| Characteristic                                                                                                                                                                                                                                                                                                                                                                                                                       | Symbol   | Min  | Typ   | Max   | Unit |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|------|-------|-------|------|
| <b>Functional Tests</b> (1,2,3,4) (In Freescale Doherty Test Fixture, 50 ohm system) $V_{DD} = 28\text{ Vdc}$ , $I_{DQA} = 500\text{ mA}$ , $V_{GSB} = 1.2\text{ Vdc}$ , $P_{out} = 24\text{ W Avg.}$ , $f_1 = 1880\text{ MHz}$ , $f_2 = 1910\text{ MHz}$ , 2-Carrier W-CDMA, IQ Magnitude Clipping, Input Signal PAR = 9.8 dB @ 0.01% Probability on CCDF. ACPR measured in 3.84 MHz Channel Bandwidth @ $\pm 5\text{ MHz}$ Offset. |          |      |       |       |      |
| Power Gain                                                                                                                                                                                                                                                                                                                                                                                                                           | $G_{ps}$ | 15.0 | 16.0  | 18.0  | dB   |
| Drain Efficiency                                                                                                                                                                                                                                                                                                                                                                                                                     | $\eta_D$ | 37.5 | 41.2  | —     | %    |
| Output Peak-to-Average Ratio @ 0.01% Probability on CCDF                                                                                                                                                                                                                                                                                                                                                                             | PAR      | 7.3  | 7.7   | —     | dB   |
| Adjacent Channel Power Ratio                                                                                                                                                                                                                                                                                                                                                                                                         | ACPR     | —    | -31.9 | -29.5 | dBc  |

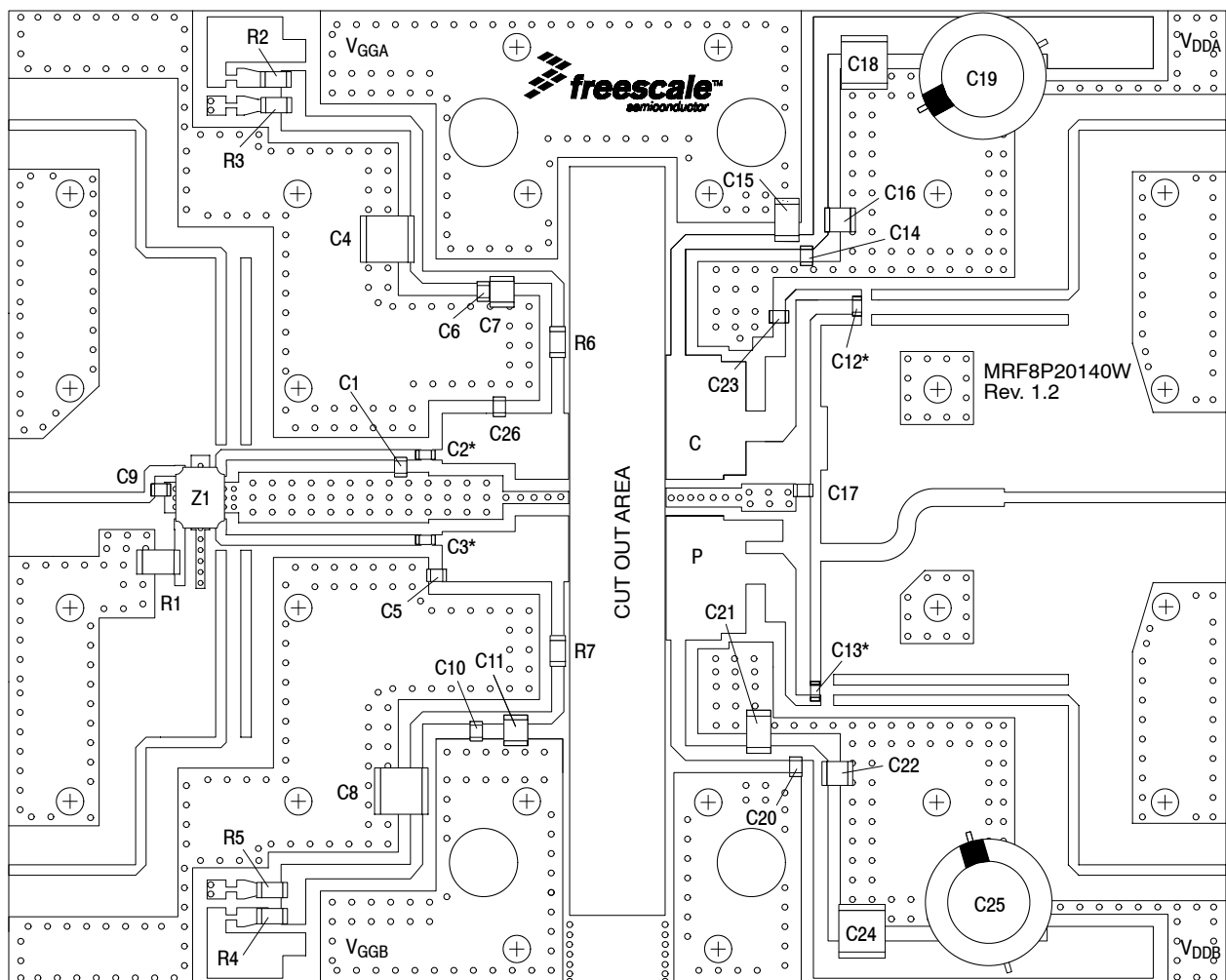
**Typical Performance over Frequency** (3) — (In Freescale Doherty Test Fixture, 50 ohm system)  $V_{DD} = 28\text{ Vdc}$ ,  $I_{DQA} = 500\text{ mA}$ ,  $V_{GSB} = 1.2\text{ Vdc}$ ,  $P_{out} = 24\text{ W Avg.}$ , Single-Carrier W-CDMA, IQ Magnitude Clipping, Input Signal PAR = 9.9 dB @ 0.01% Probability on CCDF. ACPR measured in 3.84 MHz Channel Bandwidth @  $\pm 5\text{ MHz}$  Offset.

| Frequency | $G_{ps}$<br>(dB) | $\eta_D$<br>(%) | Output PAR<br>(dB) | ACPR<br>(dBc) |
|-----------|------------------|-----------------|--------------------|---------------|
| 1880 MHz  | 16.0             | 42.8            | 8.0                | -31.0         |
| 1920 MHz  | 16.0             | 43.7            | 8.1                | -32.6         |
| 2025 MHz  | 15.9             | 42.0            | 8.1                | -31.2         |

**Typical Performances** (3) (In Freescale Doherty Test Fixture, 50 ohm system)  $V_{DD} = 28\text{ Vdc}$ ,  $I_{DQA} = 500\text{ mA}$ ,  $V_{GSB} = 1.2\text{ Vdc}$ , 1880-2025 MHz Bandwidth

|                                                                                                                                                                                    |                    |   |       |   |       |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---|-------|---|-------|
| $P_{out}$ @ 1 dB Compression Point, CW                                                                                                                                             | P1dB               | — | 140   | — | W     |
| $P_{out}$ @ 3 dB Compression Point (5)                                                                                                                                             | P3dB               | — | 170   | — | W     |
| IMD Symmetry @ 24 W PEP, $P_{out}$ where IMD Third Order Intermodulation $\cong 30\text{ dBc}$<br>(Delta IMD Third Order Intermodulation between Upper and Lower Sidebands > 2 dB) | IMD <sub>sym</sub> | — | 133   | — | MHz   |
| VBW Resonance Point<br>(IMD Third Order Intermodulation Inflection Point)                                                                                                          | VBW <sub>res</sub> | — | 240   | — | MHz   |
| Gain Flatness in 145 MHz Bandwidth @ $P_{out} = 24\text{ W Avg.}$                                                                                                                  | $G_F$              | — | 0.25  | — | dB    |
| Gain Variation over Temperature<br>(-30°C to +85°C)                                                                                                                                | $\Delta G$         | — | 0.013 | — | dB/°C |
| Output Power Variation over Temperature<br>(-30°C to +85°C) (6)                                                                                                                    | $\Delta P_{1dB}$   | — | 0.003 | — | dB/°C |

1.  $V_{DDA}$  and  $V_{ddb}$  must be tied together and powered by a single DC power supply.
2. Part internally matched both on input and output.
3. Measurement made with device in a Symmetrical Doherty configuration.
4. Measurement made with device in straight lead configuration before any lead forming operation is applied. Lead forming is used for gull wing (GHS) parts.
5.  $P_{3dB} = P_{avg} + 7.0\text{ dB}$  where  $P_{avg}$  is the average output power measured using an unclipped W-CDMA single-carrier input signal where output PAR is compressed to 7.0 dB @ 0.01% probability on CCDF.



Note 1: \* denotes that C2, C3, C12 and C13 are mounted vertically.

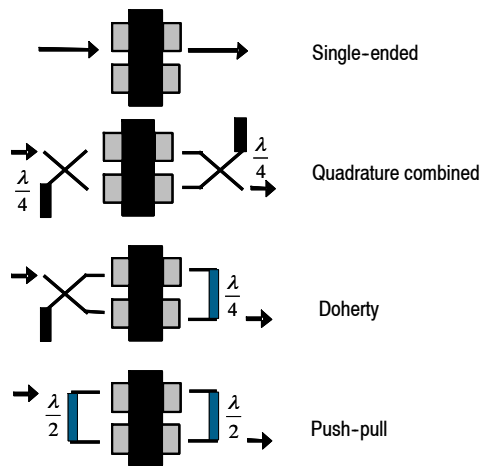
Note 2: V<sub>DDA</sub> and V<sub>ddb</sub> must be tied together and powered by a single DC power supply.

**Figure 2. MRF8P20140WHR3(WHSR3) Test Circuit Component Layout**

**Table 5. MRF8P20140WHR3(WHSR3) Test Circuit Component Designations and Values**

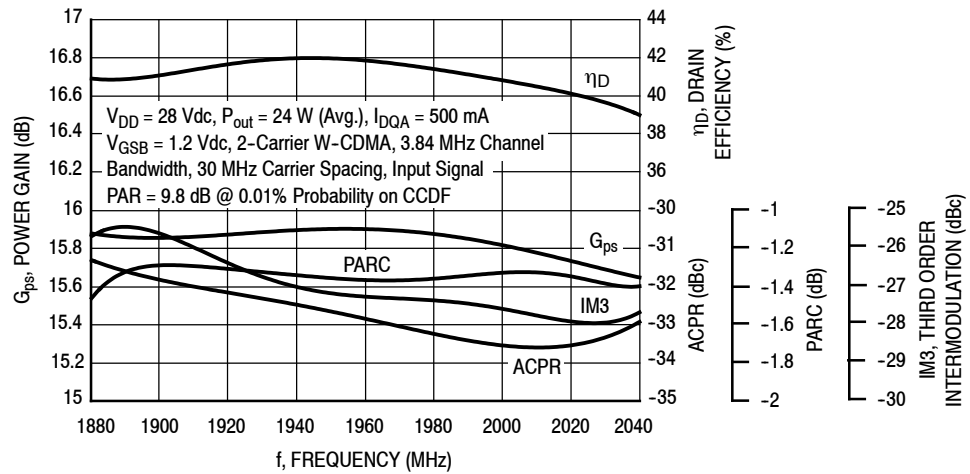
| Part                        | Description                                 | Part Number        | Manufacturer  |
|-----------------------------|---------------------------------------------|--------------------|---------------|
| C1                          | 0.6 pF Chip Capacitor                       | ATC600F0R6BT250XT  | ATC           |
| C2, C3                      | 8.2 pF Chip Capacitors                      | ATC600F8R2BT250XT  | ATC           |
| C4, C8, C18, C24            | 10 $\mu$ F, 50 V Chip Capacitors            | GRM55DR61H106KA88L | Murata        |
| C5                          | 1.2 pF Chip Capacitor                       | ATC600F1R2BT250XT  | ATC           |
| C6, C10, C12, C13, C14, C20 | 12 pF Chip Capacitors                       | ATC600F120JT250XT  | ATC           |
| C7, C11                     | 10 $\mu$ F, 32 V Chip Capacitors            | GRM32ER61H106KA12L | Murata        |
| C9, C17                     | 0.1 pF Chip Capacitors                      | ATC600F0R1BT250XT  | ATC           |
| C15, C21                    | 6.8 $\mu$ F, 50 V Chip Capacitors           | C4532X7R1H685KT    | TDK           |
| C16, C22                    | 2.2 $\mu$ F, 100 V Chip Capacitors          | C3225X7R2A225KT    | TDK           |
| C19, C25                    | 220 $\mu$ F, 100 V Chip Capacitors          | EEV-FK2A221M       | Panasonic-ECG |
| C23                         | 0.2 pF Chip Capacitor                       | ATC600F0R2BT250XT  | ATC           |
| C26                         | 1.5 pF Chip Capacitor                       | ATC600F1R5BT250XT  | ATC           |
| R1                          | 50 $\Omega$ , Chip Resistor                 | ATCCW12010T0050GBK | ATC           |
| R2, R3, R4, R5              | 1.5 k $\Omega$ , 1/4 W Chip Resistors       | CRCW12061K50FKEA   | Vishay        |
| R6, R7                      | 2.2 $\Omega$ , 1/4 W Chip Resistors         | CRCW12062R2FNEA    | Vishay        |
| Z1                          | 1700-2000 MHz Band 90°, 3 dB Hybrid Coupler | 1P503S             | Anaren        |
| PCB                         | 0.020", $\epsilon_r = 3.5$                  | R04350B            | Rogers        |

**MRF8P20140WHR3 MRF8P20140WHSR3 MRF8P20140WGHSR3**

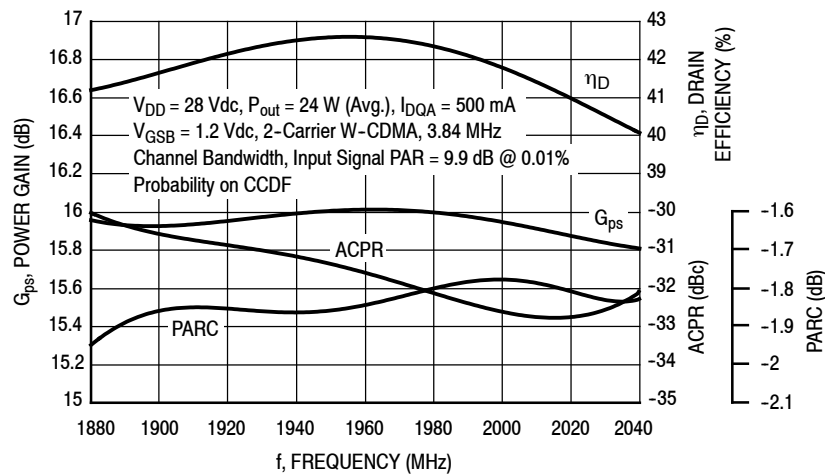


**Figure 3. Possible Circuit Topologies**

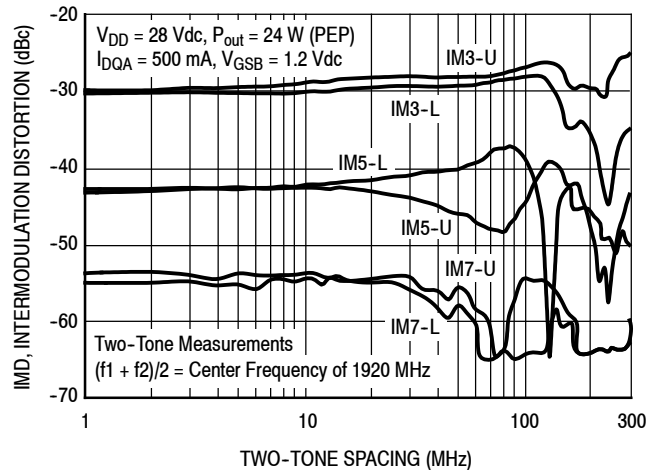
## TYPICAL CHARACTERISTICS



**Figure 4. 2-Carrier Output Peak-to-Average Ratio Compression (PARC) Broadband Performance @  $P_{out} = 24$  Watts Avg.**

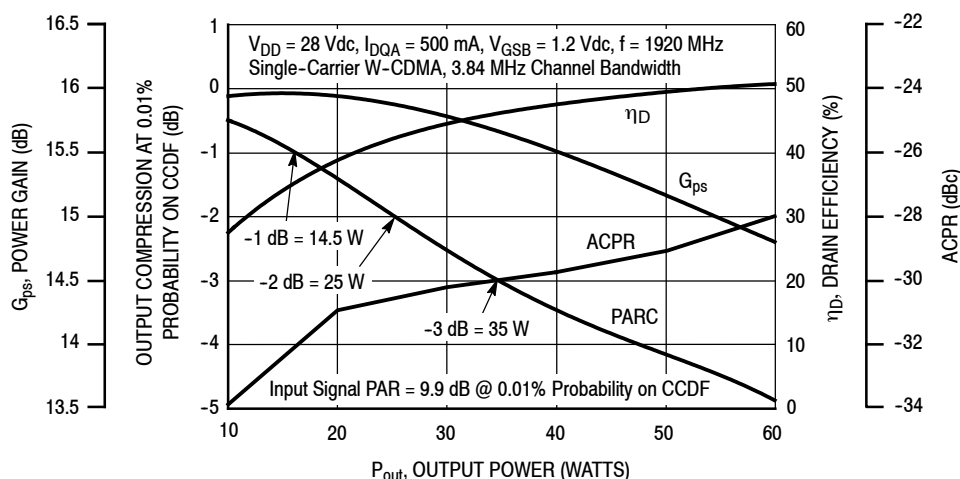


**Figure 5. Single-Carrier Output Peak-to-Average Ratio Compression (PARC) Broadband Performance @  $P_{out} = 24$  Watts Avg.**

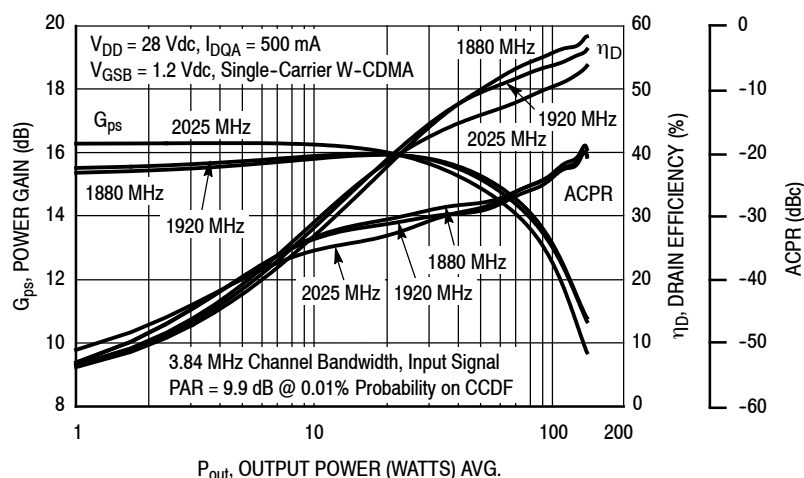


**Figure 6. Intermodulation Distortion Products versus Two-Tone Spacing**

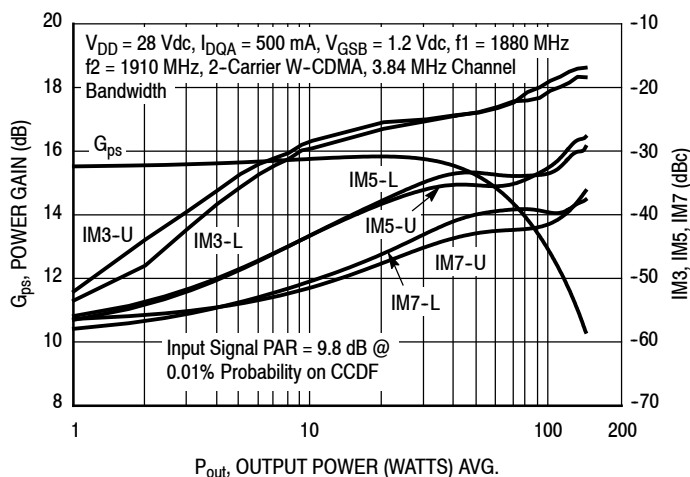
## TYPICAL CHARACTERISTICS



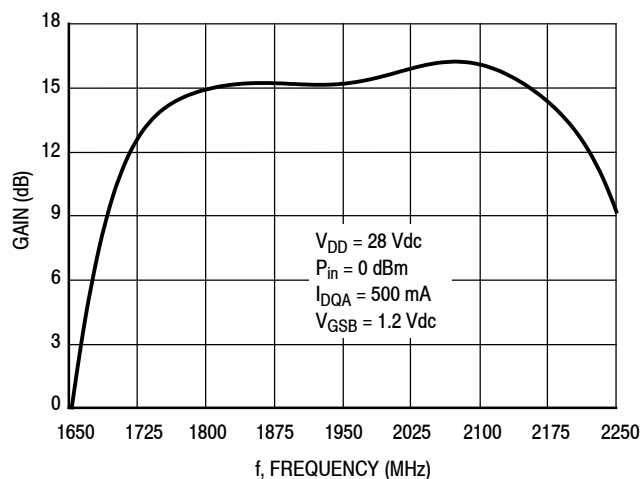
**Figure 7. Output Peak-to-Average Ratio Compression (PARC) versus Output Power**



**Figure 8. Single-Carrier W-CDMA Power Gain, Drain Efficiency and ACPR versus Output Power**



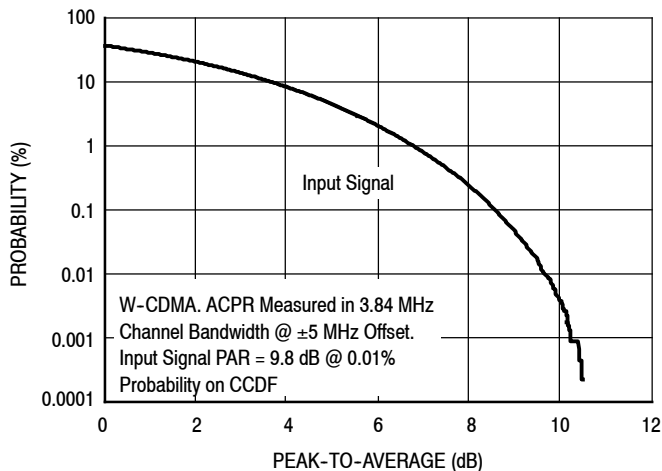
**Figure 9. 2-Carrier W-CDMA Power Gain, IM3, IM5, IM7 versus Output Power**



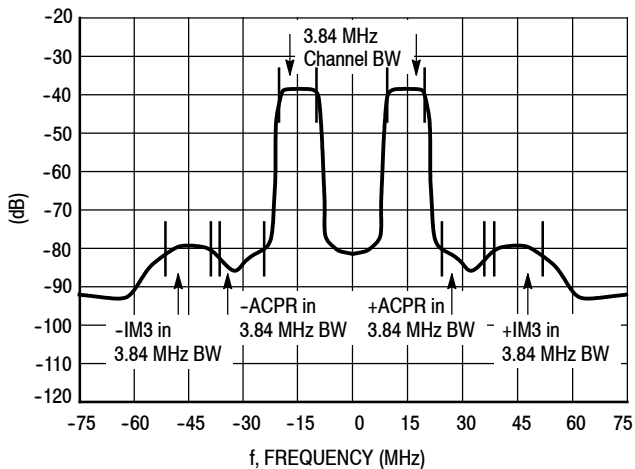
**Figure 10. Broadband Frequency Response**

MRF8P20140WHR3 MRF8P20140WHSR3 MRF8P20140WGHSR3

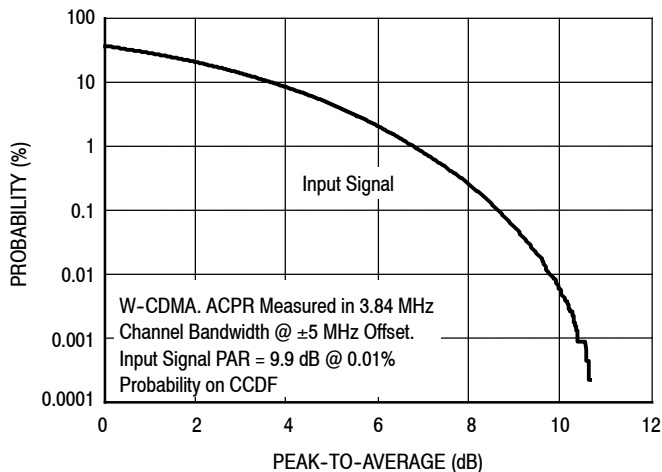
## W-CDMA TEST SIGNAL



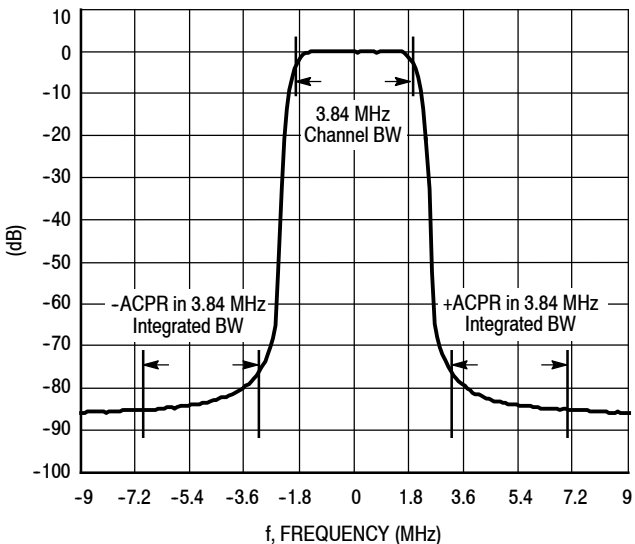
**Figure 11. CCDF W-CDMA IQ Magnitude Clipping, 2-Carrier Test Signal**



**Figure 12. 2-Carrier W-CDMA Spectrum**



**Figure 13. CCDF W-CDMA IQ Magnitude Clipping, Single-Carrier Test Signal**



**Figure 14. Single-Carrier W-CDMA Spectrum**

$V_{DD} = 28 \text{ Vdc}$ ,  $I_{DQA} = 500 \text{ mA}$ , Pulsed CW, 10  $\mu\text{sec}(\text{on})$ , 10% Duty Cycle

| f<br>(MHz) | $Z_{\text{source}}$<br>( $\Omega$ ) | $Z_{\text{load}}^{(1)}$<br>( $\Omega$ ) | Max Output Power |     |              |       |     |              |
|------------|-------------------------------------|-----------------------------------------|------------------|-----|--------------|-------|-----|--------------|
|            |                                     |                                         | P1dB             |     |              | P3dB  |     |              |
|            |                                     |                                         | (dBm)            | (W) | $\eta_D$ (%) | (dBm) | (W) | $\eta_D$ (%) |
| 1880       | 5.35 - j5.03                        | 2.36 - j4.84                            | 49.7             | 93  | 53.7         | 50.5  | 113 | 56.2         |
| 1930       | 7.39 - j5.10                        | 2.57 - j4.73                            | 50.0             | 100 | 56.9         | 50.8  | 119 | 59.3         |
| 1990       | 9.46 - j1.71                        | 2.48 - j5.11                            | 50.0             | 100 | 56.4         | 50.7  | 118 | 58.6         |
| 2025       | 9.30 + j0.80                        | 2.50 - j5.30                            | 50.0             | 100 | 56.7         | 50.7  | 118 | 59.1         |

(1) Load impedance for optimum P1dB power.

$Z_{\text{source}}$  = Impedance as measured from gate contact to ground.

$Z_{\text{load}}$  = Impedance as measured from drain contact to ground.

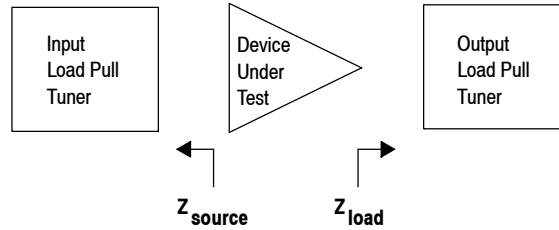


Figure 15. Carrier Side Load Pull Performance — Maximum P1dB Tuning

$V_{DD} = 28 \text{ Vdc}$ ,  $I_{DQA} = 500 \text{ mA}$ , Pulsed CW, 10  $\mu\text{sec}(\text{on})$ , 10% Duty Cycle

| f<br>(MHz) | $Z_{\text{source}}$<br>( $\Omega$ ) | $Z_{\text{load}}^{(1)}$<br>( $\Omega$ ) | Max Drain Efficiency |     |              |       |     |              |
|------------|-------------------------------------|-----------------------------------------|----------------------|-----|--------------|-------|-----|--------------|
|            |                                     |                                         | P1dB                 |     |              | P3dB  |     |              |
|            |                                     |                                         | (dBm)                | (W) | $\eta_D$ (%) | (dBm) | (W) | $\eta_D$ (%) |
| 1880       | 5.35 - j5.03                        | 6.91 - j4.37                            | 47.6                 | 57  | 64.6         | 48.2  | 67  | 65.2         |
| 1930       | 7.39 - j5.10                        | 6.36 - j3.60                            | 48.0                 | 63  | 67.3         | 48.6  | 72  | 68.3         |
| 1990       | 9.46 - j1.71                        | 5.61 - j3.11                            | 48.0                 | 63  | 67.2         | 48.6  | 72  | 67.8         |
| 2025       | 9.30 + j0.80                        | 5.28 - j2.88                            | 47.9                 | 61  | 66.5         | 48.5  | 70  | 67.3         |

(1) Load impedance for optimum P1dB efficiency.

$Z_{\text{source}}$  = Impedance as measured from gate contact to ground.

$Z_{\text{load}}$  = Impedance as measured from drain contact to ground.

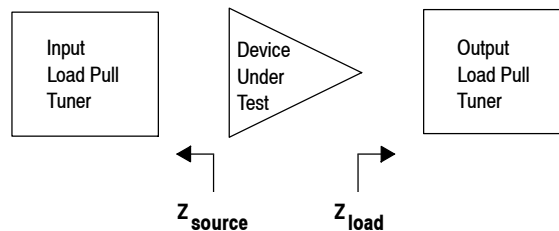
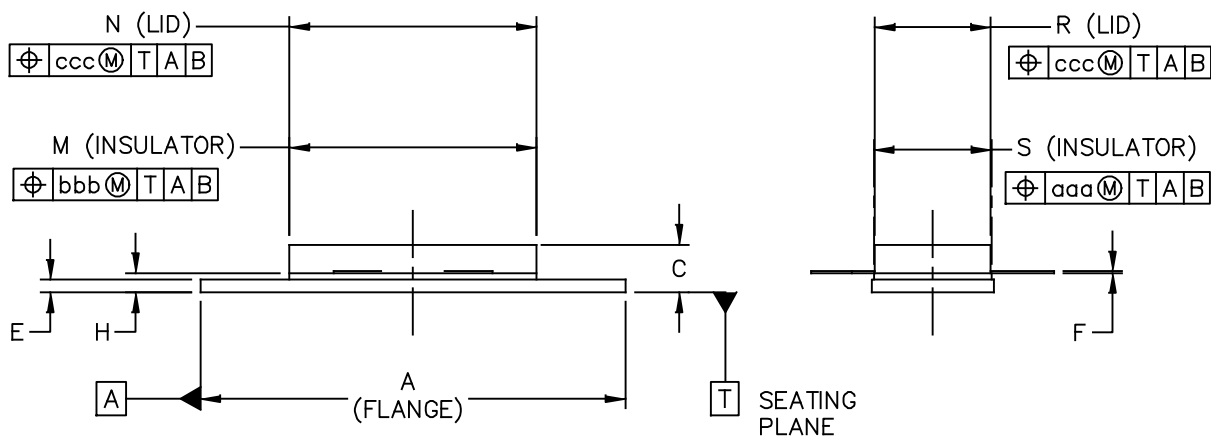
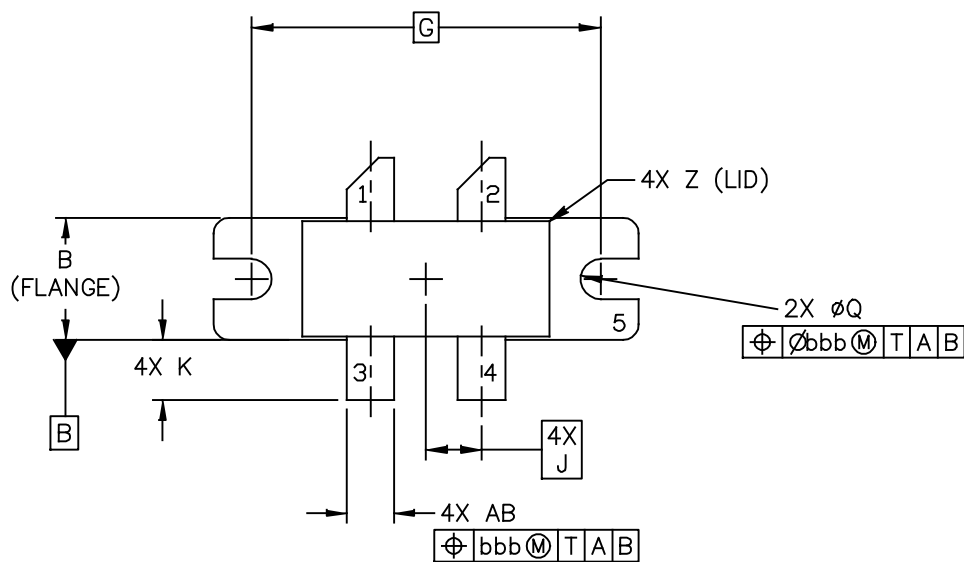


Figure 16. Carrier Side Load Pull Performance — Maximum Efficiency Tuning

# PACKAGE DIMENSIONS



|                                                         |  |                    |                          |                            |             |
|---------------------------------------------------------|--|--------------------|--------------------------|----------------------------|-------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |  | MECHANICAL OUTLINE |                          | PRINT VERSION NOT TO SCALE |             |
| TITLE:<br><br>NI 780-4                                  |  |                    | DOCUMENT NO: 98ASA10793D |                            | REV: 0      |
|                                                         |  |                    | CASE NUMBER: 465M-01     |                            | 27 MAR 2007 |
|                                                         |  |                    | STANDARD: NON-JEDEC      |                            |             |

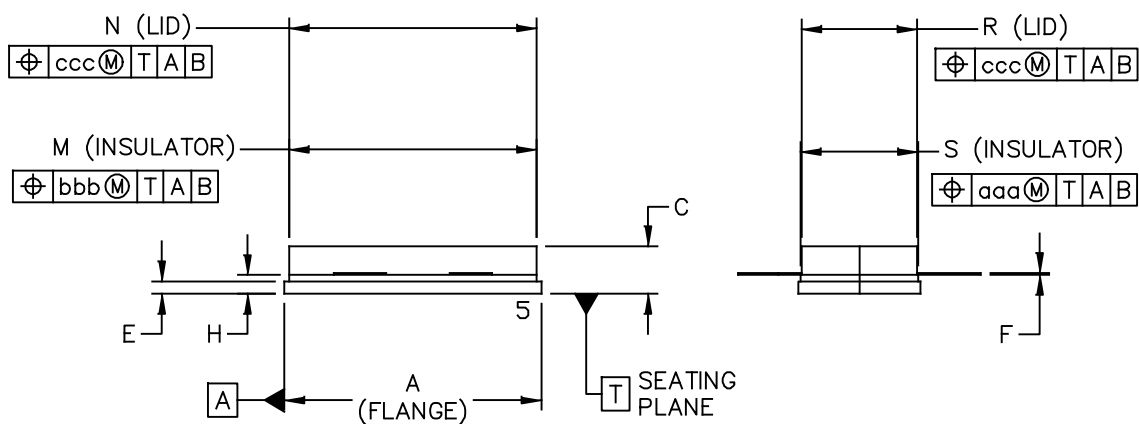
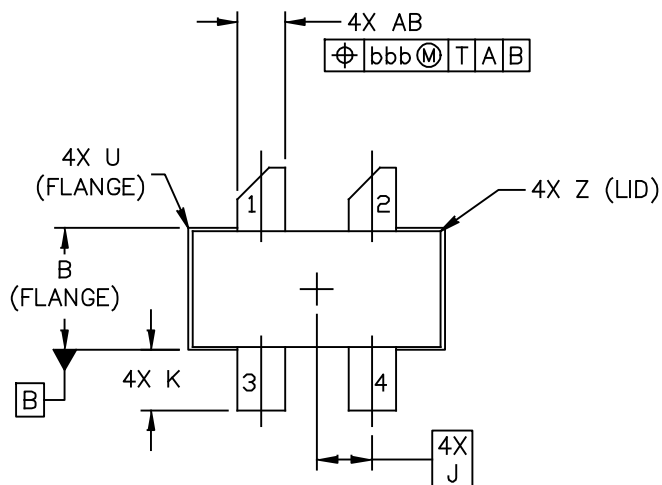
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY.

STYLE 1:

- PIN
1. DRAIN
  2. DRAIN
  3. GATE
  4. GATE
  5. SOURCE

| INCH                                                    |           |       | MILLIMETER         |       | INCH                     |                            |      | MILLIMETER  |      |
|---------------------------------------------------------|-----------|-------|--------------------|-------|--------------------------|----------------------------|------|-------------|------|
| DIM                                                     | MIN       | MAX   | MIN                | MAX   | DIM                      | MIN                        | MAX  | MIN         | MAX  |
| A                                                       | 1.335     | 1.345 | 33.91              | 34.16 | R                        | .365                       | .375 | 9.27        | 9.53 |
| B                                                       | .380      | .390  | 9.65               | 9.91  | S                        | .365                       | .375 | 9.27        | 9.52 |
| C                                                       | .125      | .170  | 3.18               | 4.32  | U                        |                            | .040 |             | 1.02 |
| E                                                       | .035      | .045  | 0.89               | 1.14  | Z                        |                            | .030 |             | 0.76 |
| F                                                       | .003      | .006  | 0.08               | 0.15  | AB                       | .145                       | .155 | 3.68        | 3.94 |
| G                                                       | 1.100 BSC |       | 27.94 BSC          |       |                          |                            |      |             |      |
| H                                                       | .057      | .067  | 1.45               | 1.7   | aaa                      | .005                       |      | 0.127       |      |
| J                                                       | .175 BSC  |       | 4.44 BSC           |       | bbb                      | .010                       |      | 0.254       |      |
| K                                                       | .170      | .210  | 4.32               | 5.33  | ccc                      | .015                       |      | 0.381       |      |
| M                                                       | .774      | .786  | 19.61              | 20.02 |                          |                            |      |             |      |
| N                                                       | .772      | .788  | 19.61              | 20.02 |                          |                            |      |             |      |
| Q                                                       | Ø.118     | Ø.138 | Ø3                 | Ø3.51 |                          |                            |      |             |      |
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| TITLE:<br><br>NI 780-4                                  |           |       |                    |       | DOCUMENT NO: 98ASA10793D |                            |      | REV: 0      |      |
|                                                         |           |       |                    |       | CASE NUMBER: 465M-01     |                            |      | 27 MAR 2007 |      |
|                                                         |           |       |                    |       | STANDARD: NON-JEDEC      |                            |      |             |      |



|                                                         |  |                          |                            |
|---------------------------------------------------------|--|--------------------------|----------------------------|
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| TITLE:<br><br>NI 780S-4                                 |  | DOCUMENT NO: 98ASA10718D | REV: A                     |
|                                                         |  | CASE NUMBER: 465H-02     | 27 MAR 2007                |
|                                                         |  | STANDARD: NON-JEDEC      |                            |

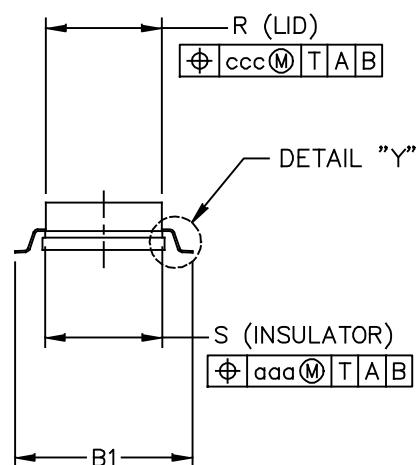
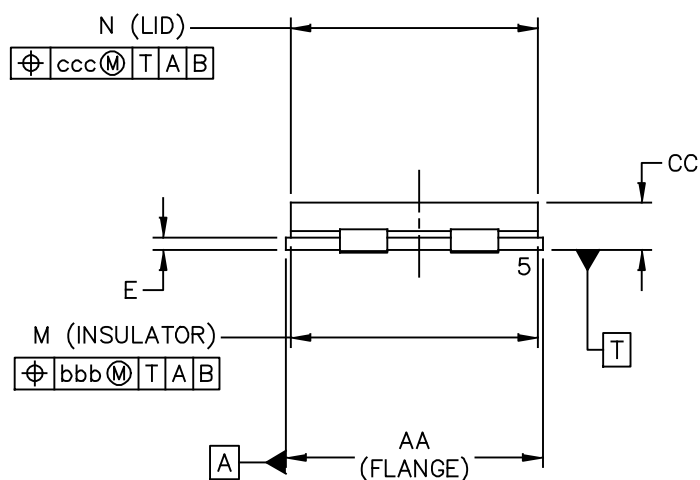
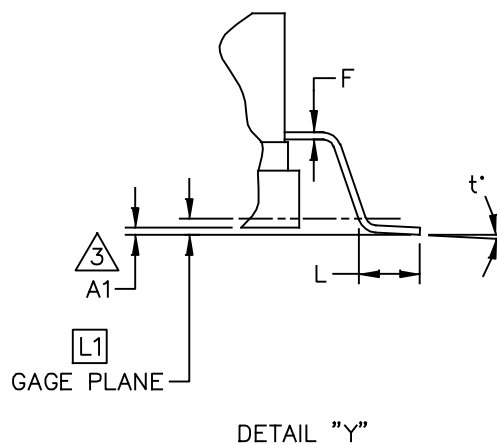
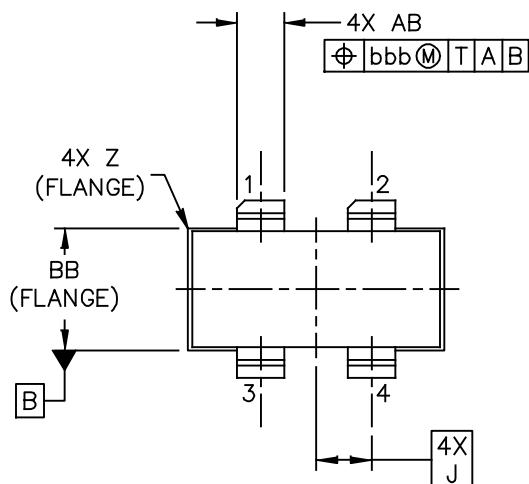
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
2. CONTROLLING DIMENSION: INCH.
3. DELETED
4. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY.

STYLE 1:

- PIN 1. DRAIN
2. DRAIN
3. GATE
4. GATE
5. SOURCE

| DIM                                                     | INCH     |      | MILLIMETER         |       | DIM                      | INCH                       |      | MILLIMETER  |        |
|---------------------------------------------------------|----------|------|--------------------|-------|--------------------------|----------------------------|------|-------------|--------|
|                                                         | MIN      | MAX  | MIN                | MAX   |                          | MIN                        | MAX  | MIN         | MAX    |
| A                                                       | .805     | .815 | 20.45              | 20.7  | U                        |                            | .040 |             | 1.02   |
| B                                                       | .380     | .390 | 9.65               | 9.91  | Z                        |                            | .030 |             | 0.76   |
| C                                                       | .125     | .170 | 3.18               | 4.32  | AB                       | .145                       | .155 | 3.68        | — 3.94 |
| E                                                       | .035     | .045 | 0.89               | 1.14  |                          |                            |      |             |        |
| F                                                       | .003     | .006 | 0.08               | 0.15  | aaa                      |                            | .005 |             | 0.127  |
| H                                                       | .057     | .067 | 1.45               | 1.7   | bbb                      |                            | .010 |             | 0.254  |
| J                                                       | .175 BSC |      | 4.44 BSC           |       | ccc                      |                            | .015 |             | 0.381  |
| K                                                       | .170     | .210 | 4.32               | 5.33  |                          |                            |      |             |        |
| M                                                       | .774     | .786 | 19.61              | 20.02 |                          |                            |      |             |        |
| N                                                       | .772     | .788 | 19.61              | 20.02 |                          |                            |      |             |        |
| R                                                       | .365     | .375 | 9.27               | 9.53  |                          |                            |      |             |        |
| S                                                       | .365     | .375 | 9.27               | 9.52  |                          |                            |      |             |        |
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| TITLE:<br><br>NI 780S-4                                 |          |      |                    |       | DOCUMENT NO: 98ASA10718D |                            |      | REV: A      |        |
|                                                         |          |      |                    |       | CASE NUMBER: 465H-02     |                            |      | 27 MAR 2007 |        |
|                                                         |          |      |                    |       | STANDARD: NON-JEDEC      |                            |      |             |        |



|                                                         |                                      |                            |
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| TITLE:<br><br>NI-780GS-4L                               | DOCUMENT NO: 98ASA00238D      REV: B |                            |
|                                                         | STANDARD: NON-JEDEC                  |                            |
|                                                         | 05 SEP 2013                          |                            |

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.

2. CONTROLLING DIMENSION: INCH.

3. DIMENSION A1 IS MEASURED WITH REFERENCE TO DATUM T. THE POSITIVE VALUE IMPLIES THAT THE PACKAGE BOTTOM IS HIGHER THAN THE LEAD BOTTOM.

| INCH                                                    |          |      | MILLIMETER         |       | INCH                                 |                            |       | MILLIMETER |       |
|---------------------------------------------------------|----------|------|--------------------|-------|--------------------------------------|----------------------------|-------|------------|-------|
| DIM                                                     | MIN      | MAX  | MIN                | MAX   | DIM                                  | MIN                        | MAX   | MIN        | MAX   |
| AA                                                      | .805     | .815 | 20.45              | 20.70 | Z                                    | R.000                      | R.040 | R0.00      | R1.02 |
| A1                                                      | .002     | .008 | 0.05               | 0.20  | AB                                   | .145                       | .155  | 3.68       | 3.94  |
| BB                                                      | .380     | .390 | 9.65               | 9.91  | t°                                   | 0°                         | 8°    | 0°         | 8°    |
| B1                                                      | .546     | .562 | 13.87              | 14.27 | aaa                                  | .005                       |       | 0.13       |       |
| CC                                                      | .125     | .170 | 3.18               | 4.32  | bbb                                  | .010                       |       | 0.25       |       |
| E                                                       | .035     | .045 | 0.89               | 1.14  | ccc                                  | .015                       |       | 0.38       |       |
| F                                                       | .003     | .006 | 0.08               | 0.15  |                                      |                            |       |            |       |
| L                                                       | .038     | .046 | 0.97               | 1.17  |                                      |                            |       |            |       |
| L1                                                      | .010 BSC |      | 0.25 BSC           |       |                                      |                            |       |            |       |
| J                                                       | .175 BSC |      | 4.44 BSC           |       |                                      |                            |       |            |       |
| M                                                       | .774     | .786 | 19.66              | 19.96 |                                      |                            |       |            |       |
| N                                                       | .772     | .788 | 19.61              | 20.02 |                                      |                            |       |            |       |
| R                                                       | .365     | .375 | 9.27               | 9.53  |                                      |                            |       |            |       |
| S                                                       | .365     | .375 | 9.27               | 9.53  |                                      |                            |       |            |       |
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| TITLE:<br><br>NI-780GS-4L                               |          |      |                    |       | DOCUMENT NO: 98ASA00238D      REV: B |                            |       |            |       |
|                                                         |          |      |                    |       | STANDARD: NON-JEDEC                  |                            |       |            |       |
|                                                         |          |      |                    |       | 05 SEP 2013                          |                            |       |            |       |

## PRODUCT DOCUMENTATION, SOFTWARE AND TOOLS

Refer to the following documents, Software and Tools to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

### Software

- Electromigration MTTF Calculator
- RF High Power Model
- .s2p File

For Software and Tools, do a Part Number search at <http://www.freescale.com>, and select the “Part Number” link. Go to the Software & Tools tab on the part’s Product Summary page to download the respective tool.

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
|----------|-----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0        | Apr. 2011 | <ul style="list-style-type: none"> <li>• Initial Release of Data Sheet</li> </ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| 1        | Nov. 2013 | <ul style="list-style-type: none"> <li>• Added part number MRF8P20140WGHSR3 (NI-780GS-4L), p. 1</li> <li>• Table 3, ESD Protection Characteristics, removed the word “Minimum” after the ESD class rating. ESD ratings are characterized during new product development but are not 100% tested during production. ESD ratings provided in the data sheet are intended to be used as a guideline when handling ESD sensitive devices, p. 2</li> <li>• Added NI-780GS-4L package isometric, p. 1, and Mechanical Outline, pp. 14-15</li> <li>• Added Electromigration MTTF Calculator and RF High Power Model availability to Product Software, p. 16</li> </ul> |

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